

SOC data sheet SOC-1040-2-3-1ps-x, λ = 1040 nm

 $\begin{array}{lll} \text{Laser wavelength} & \lambda = 1040 \text{ nm} \\ & \lambda_0 = 2 \text{ }\% \\ & \text{Transmittance} & T = 3 \text{ }\% \\ & \text{Reflectance} & R = 95 \text{ }\% \\ & \text{Modulation depth} & \Delta R = 1.2 \text{ }\% \\ & \text{Non-saturable loss} & A_{\text{ns}} = 0.8 \text{ }\% \\ & \text{Saturation fluence} & \Phi_{\text{sat}} = 90 \text{ }\mu\text{J/cm}^2 \end{array}$

Relaxation time constant $\tau \sim 1 \text{ ps}$

Chip area 5.0 mm x 5.0 mm; other dimensions on request

Chip thickness 625 µm; semi-insulating GaAs

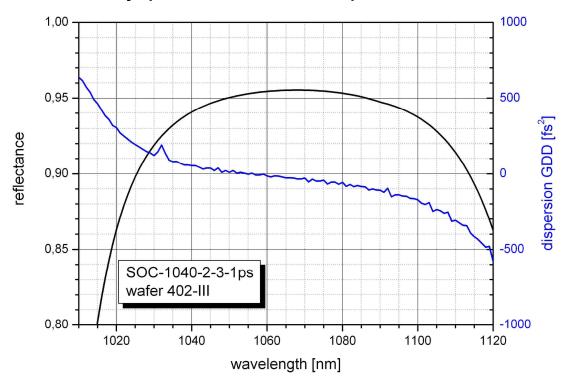
Front side protection with a dielectric layer

Back side AR coating the SOC back side is polished and antireflection coated for 1064 nm

Mounting option **x** denotes the type of mounting as follows:

x = 0 unmounted
x = 12.7 g glued on a gilded Cu-cylinder with 12.7 mm Ø and 4 mm Ø center hole
x = 25.0 g glued on a gilded Cu-cylinder with 25. mm Ø and 4 mm Ø center hole
x = 25.4 g glued on a gilded Cu-cylinder with 25.4 mm Ø and 4 mm Ø center hole
x = FC mounted on a 1 m single mode fiber cable with FC connector

Low intensity spectral reflectance and dispersion coefficient D₂





Low spectral intensity transmittance and dispersion coefficient D₂

